



## DESCRIPTION

The MXD30N50 uses advanced trench technology to provide excellent  $R_{DS(ON)}$  and low gate charge. It can be used in a wide variety of applications.



## GENERAL FEATURES

- $V_{DS}=30V$ ,  $I_D=50A$   
 $R_{DS(ON)}(Typ.)=11m\Omega$  @  $V_{GS}=4.5V$   
 $R_{DS(ON)}(Typ.)=7m\Omega$  @  $V_{GS}=10V$
- High Power and current handling capability
- Lead free product is acquired
- Surface Mount Package

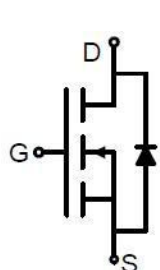


## APPLICATION

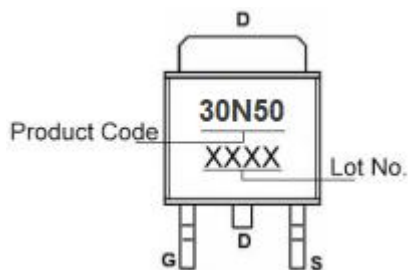
- Battery management
- Motor controller and driver
- PWM applications
- Load switch



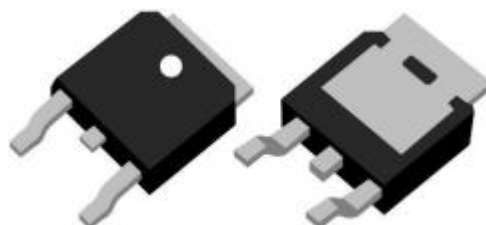
## PINOUT



Schematic diagram



Marking and pin Assignment



TO-252-2L top & bottom view



## ORDERING INFORMATION

| Part Number | Storage Temperature | Package   | Devices Per Reel |
|-------------|---------------------|-----------|------------------|
| MX30N50     | -55°C to 150°C      | TO-252-2L | -                |



## ABSOLUTE MAXIMUM RATINGS( $T_C=25^\circ C$ unless otherwise noted)

| Parameter                                        | Symbol         | Limit      | Unit       |
|--------------------------------------------------|----------------|------------|------------|
| Drain-Source Voltage                             | $V_{DS}$       | 30         | V          |
| Gate-Source Voltage                              | $V_{GS}$       | $\pm 20$   | V          |
| Drain Current-Continuous                         | $I_D$          | 50         | A          |
| Drain Current-Continuous( $T_C=100^\circ C$ )    | $I_D$          | 35         | A          |
| Pulsed Drain Current <sup>(Note1)</sup>          | $I_{DM}$       | 140        | A          |
| Maximum Power Dissipation                        | $P_D$          | 37.5       | W          |
| Operating Junction and Storage Temperature Range | $T_J, T_{STG}$ | -55 to 150 | $^\circ C$ |



## THERMAL RESISTANCE

|                                                         |                 |   |              |
|---------------------------------------------------------|-----------------|---|--------------|
| Thermal Resistance, Junction-to-Case <sup>(Note2)</sup> | $R_{\theta JC}$ | 4 | $^\circ C/W$ |
|---------------------------------------------------------|-----------------|---|--------------|

Note 1. Repetitive Rating: Pulse width limited by maximum junction temperature.

Note 2. Surface Mounted on FR4 Board,  $t \leq 10$  sec.


**ELECTRICAL CHARACTERISTICS** ( $T_A=25^{\circ}\text{C}$  unless otherwise noted)

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|-----------|--------|------------|-----|-----|-----|------|
|-----------|--------|------------|-----|-----|-----|------|

**Off Characteristics**

|                                 |            |                             |    |   |           |         |
|---------------------------------|------------|-----------------------------|----|---|-----------|---------|
| Drain-Source Breakdown Voltage  | $BV_{DSS}$ | $V_{GS}=0V, I_D=250\mu A$   | 30 | - | -         | V       |
| Zero Gate Voltage Drain Current | $I_{DSS}$  | $V_{DS}=30V, V_{GS}=0V$     | -  | - | 1         | $\mu A$ |
| Gate-Body Leakage Current       | $I_{GSS}$  | $V_{GS}=\pm 20V, V_{DS}=0V$ | -  | - | $\pm 100$ | nA      |

**On Characteristics** (Note2)

|                                  |              |                               |     |     |     |            |
|----------------------------------|--------------|-------------------------------|-----|-----|-----|------------|
| Gate Threshold Voltage           | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$ | 1.0 | 1.5 | 2.2 | V          |
| Drain-Source On-State Resistance | $R_{DS(on)}$ | $V_{GS}=4.5V, I_D=13A$        | -   | 11  | 14  | m $\Omega$ |
|                                  |              | $V_{GS}=10V, I_D=16A$         | -   | 7   | 8.5 | m $\Omega$ |
| Forward Transconductance         | $g_{FS}$     | $V_{DS}=5V, I_D=20A$          | -   | 42  | -   | S          |

**Dynamic Characteristics** (Note3)

|                              |           |                                   |   |      |   |          |
|------------------------------|-----------|-----------------------------------|---|------|---|----------|
| Input Capacitance            | $C_{iss}$ | $V_{DS}=15V, V_{GS}=0V, F=1.0MHz$ | - | 1300 | - | pF       |
| Output Capacitance           | $C_{oss}$ |                                   | - | 140  | - | pF       |
| Reverse Transfer Capacitance | $C_{rss}$ |                                   | - | 130  | - | pF       |
| Gate Resistance              | $R_g$     | $V_{DS}=0V, V_{GS}=0V, F=1.0MHz$  | - | 2.2  | - | $\Omega$ |

**Switching Characteristics**

|                     |              |                                                            |   |     |   |    |
|---------------------|--------------|------------------------------------------------------------|---|-----|---|----|
| Turn-on Delay Time  | $t_{d(on)}$  | $V_{DD}=15V, I_D=2A, R_L=1\Omega, V_{GS}=10V, R_G=3\Omega$ | - | 7.2 | - | nS |
| Turn-on Rise Time   | $t_r$        |                                                            | - | 12  | - | nS |
| Turn-Off Delay Time | $t_{d(off)}$ |                                                            | - | 23  | - | nS |
| Turn-Off Fall Time  | $t_f$        |                                                            | - | 8   | - | nS |
| Total Gate Charge   | $Q_g$        | $V_{DS}=15V, I_D=25A, V_{GS}=10V$                          | - | 28  | - | nC |
| Gate-Source Charge  | $Q_{gs}$     |                                                            | - | 3.5 | - | nC |
| Gate-Drain Charge   | $Q_{gd}$     |                                                            | - | 7   | - | nC |

**Drain-Source Diode Characteristics**

|                               |          |                     |   |   |     |   |
|-------------------------------|----------|---------------------|---|---|-----|---|
| Diode Forward Voltage (Note2) | $V_{SD}$ | $V_{GS}=0V, I_S=1A$ | - | - | 1.2 | V |
| Diode Forward Current (Note1) | $I_S$    |                     | - | - | 40  | A |

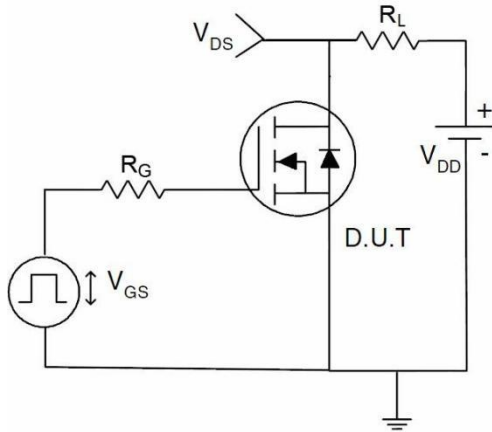
Note 1. Surface Mounted on FR4 Board,  $t \leq 10$  sec.

Note 2. Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .

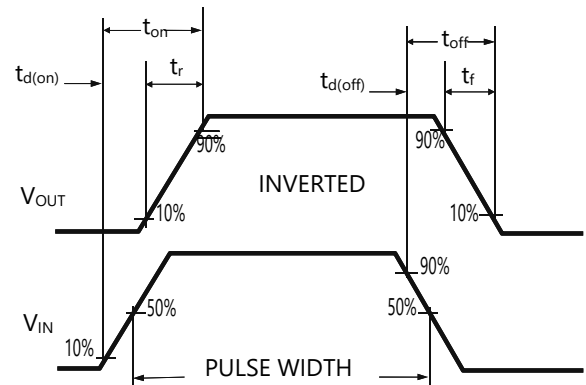
Note 3. Guaranteed by design, not subject to product.

## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

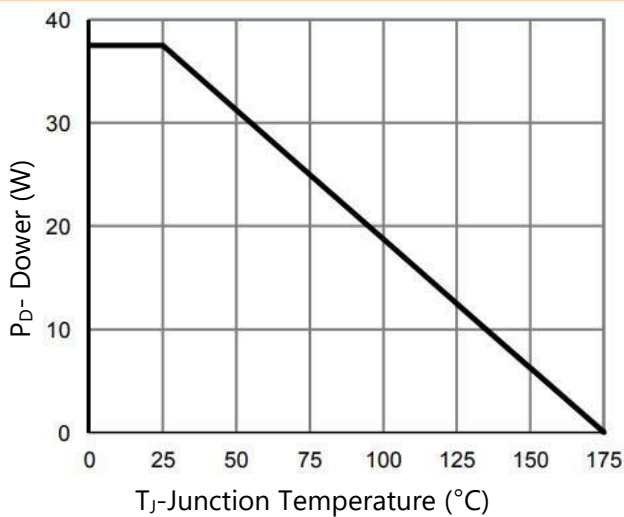
**Figure 1. Switching Test Circuit**



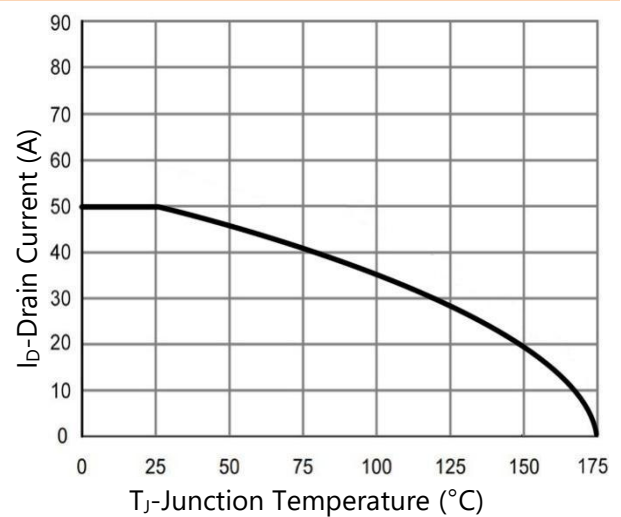
**Figure 2. Switching Waveform**



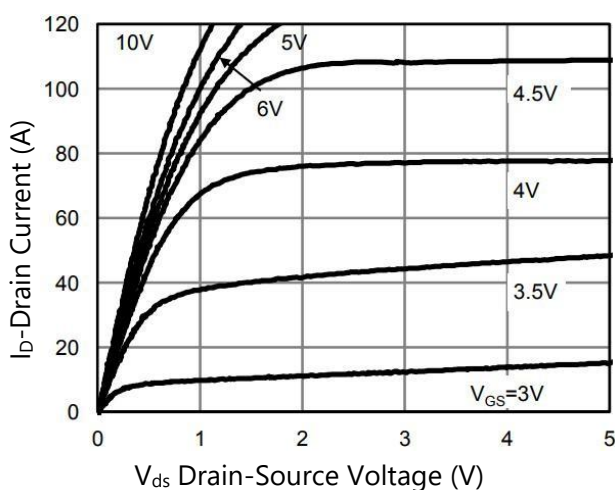
**Figure 3. Power Dissipation**



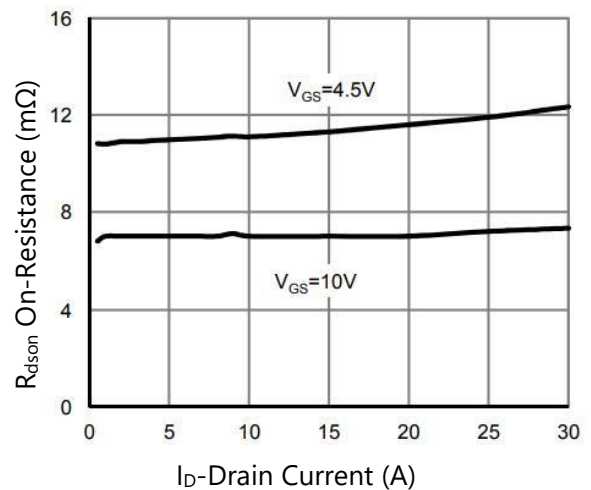
**Figure 4. Drain Current**



**Figure 5. Output Characteristics**



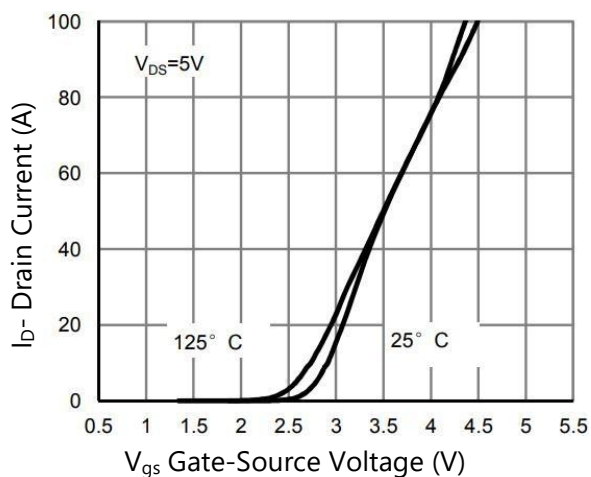
**Figure 6.  $R_{ds(on)}$  vs Drain Current**



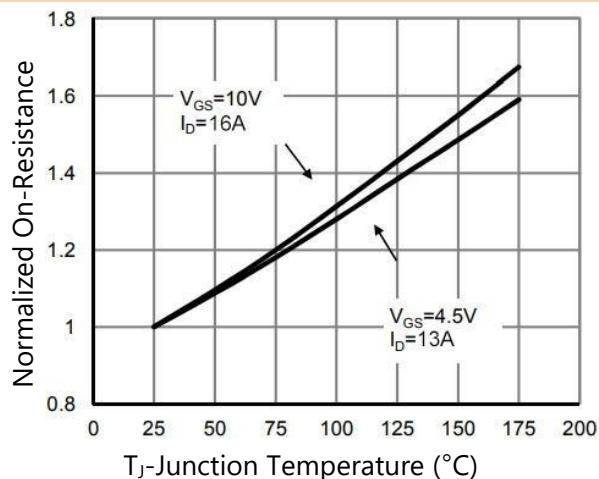


## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

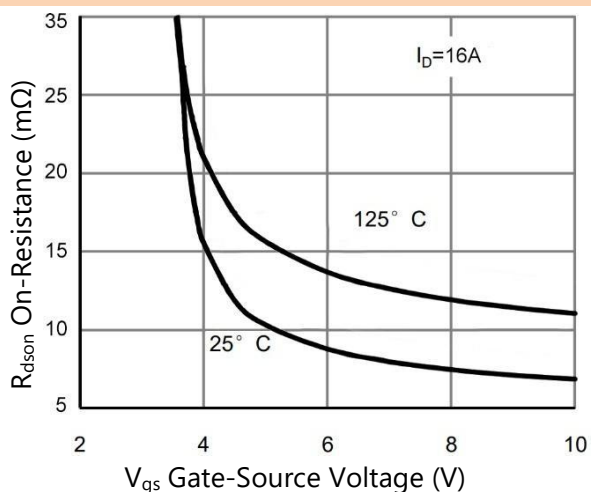
**Figure 7. Transfer Characteristics**



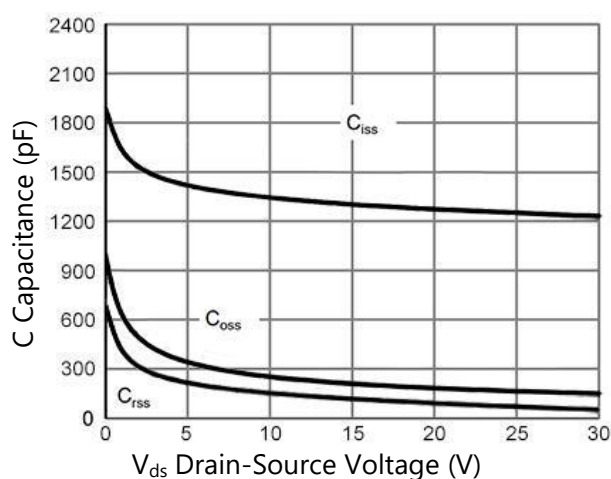
**Figure 8.  $R_{dson}$  vs Junction Temperature**



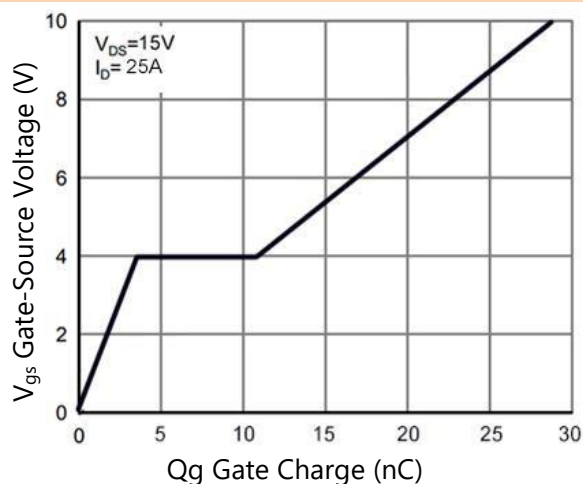
**Figure 9.  $R_{dson}$  vs  $V_{GS}$**



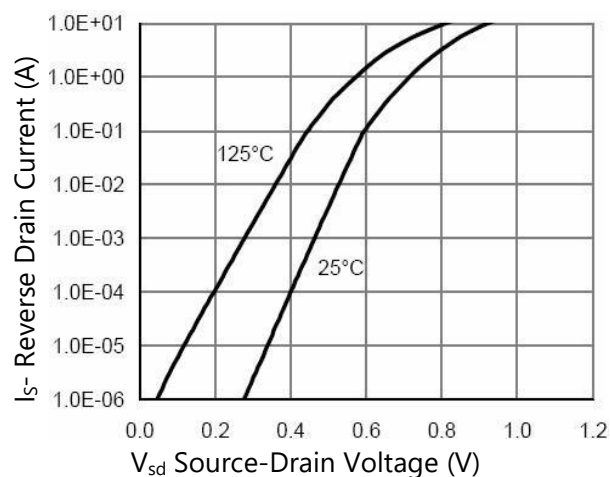
**Figure 10. Capacitance vs  $V_{DS}$**



**Figure 11. Gate Charge**



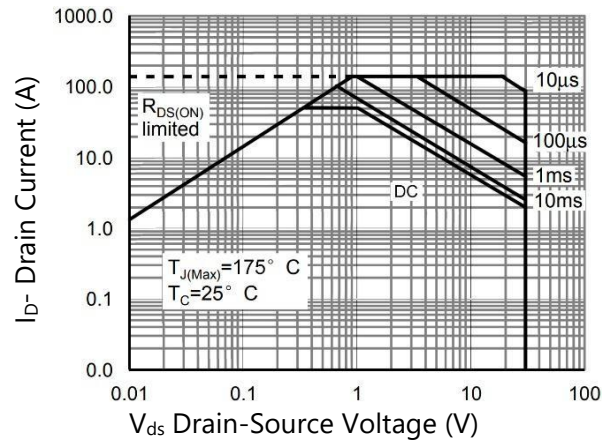
**Figure 12. Source- Drain Diode Forward**



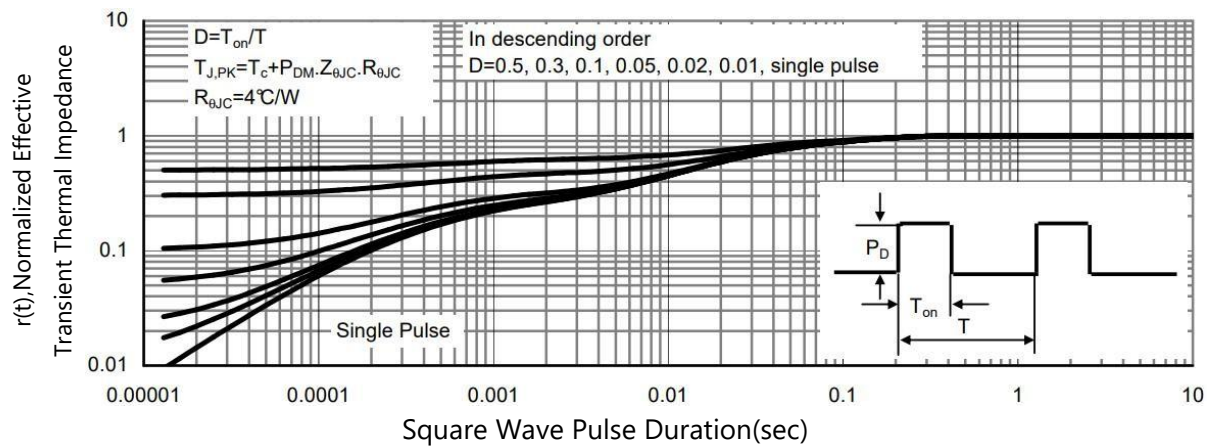


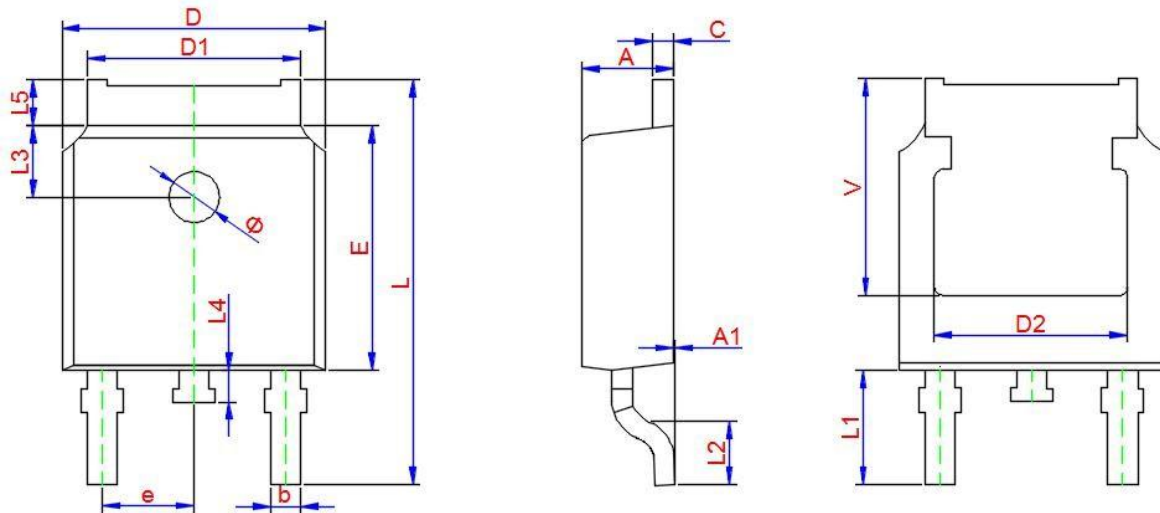
## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

**Figure 13. Safe Operation Area**



**Figure 14. Normalized Maximum Transient Thermal Impedance**




**PACKAGE INFORMATION**
**TO-252-2L**


| Symbol | Dimensions in Millimeters |        |        |
|--------|---------------------------|--------|--------|
|        | Min.                      | Typ.   | Max.   |
| A      | 2.200                     | 2.300  | 2.400  |
| A1     | 0.000                     | -      | 0.127  |
| D      | 6.500                     | 6.600  | 6.700  |
| D1     | 5.100                     | 5.330  | 5.460  |
| C      | 0.450                     | 0.500  | 0.600  |
| D2     | 4.830 TYP.                |        |        |
| E      | 6.000                     | 6.100  | 6.200  |
| e      | 2.186                     | 2.286  | 2.386  |
| L      | 9.800                     | 10.100 | 10.400 |
| L1     | 2.900 TYP.                |        |        |
| L2     | 1.400                     | 1.500  | 1.600  |
| L3     | 1.800 TYP.                |        |        |
| L4     | 0.600                     | 0.800  | 1.000  |
| L5     | 0.900                     | -      | 1.250  |
| Φ      | 1.100.                    | -      | 1.300  |
| θ      | 0°                        | -      | 8°     |
| V      | 5.350                     |        |        |